

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









N-Channel Power MOSFET

700V, 11A, 0.38Ω

FEATURES

- Super-Junction technology
- High performance due to small figure-of-merit
- High ruggedness performance
- High commutation performance

ΛD	DI	ICA	TI	\mathbf{ON}

- Power Supply
- Lighting

KEY PERFORMANCE PARAMETERS					
PARAMETER VALUE UNIT					
V_{DS}	700	V			
R _{DS(on)} (max)	0.38	Ω			
Q_g	18.8	nC			





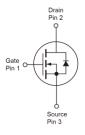


Version: E1706









Notes: MSL 3 (Moisture Sensitivity Level) for TO-252 (D-PAK) per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER		SYMBOL	ITO-220	IPAK/DPAK	UNIT	
Drain-Source Voltage		V _{DS}	700		V	
Gate-Source Voltage		V_{GS}	±30		V	
O D (Note 1)	$T_C = 25^{\circ}C$		11 6.6		A	
Continuous Drain Current (Note 1)	$T_C = 100$ °C					
Pulsed Drain Current (Note 2)		I _{DM}	33		Α	
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	33	125	W	
Single Pulsed Avalanche Energy (Note 3)		E _{AS}	156		mJ	
Single Pulsed Avalanche Current (Note 3)		I _{AS}	2.5		Α	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	- 55 to +150		°C	

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ITO-220	IPAK/DPAK	TINU	
Junction to Case Thermal Resistance	R _{eJC}	3.8	1	°C/W	
Junction to Ambient Thermal Resistance	R _{eJA}	62		°C/W	

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air.





ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV _{DSS}	700			V
Gate Threshold Voltage	$V_{DS}=V_{GS},\ I_D=250\mu A$	$V_{GS(TH)}$	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 30V$, $V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 700V, V_{GS} = 0V$	I _{DSS}			1	μΑ
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 3.3A$	R _{DS(on)}		0.33	0.38	Ω
Dynamic (Note 5)						
Total Gate Charge	$V_{DS} = 380V, I_{D} = 11A,$ $V_{GS} = 10V$	Q_g		18.8		
Gate-Source Charge		Q_{gs}		3.7		nC
Gate-Drain Charge		Q_{gd}		5.6		
Input Capacitance	$V_{DS} = 100V, V_{GS} = 0V,$	C _{iss}		981		. –
Output Capacitance	f = 1.0MHz	C _{oss}		58		pF
Gate Resistance	F = 1MHz, open drain	R_g		3.3		Ω
Switching (Note 6)						
Turn-On Delay Time		t _{d(on)}		32		
Turn-On Rise Time	$V_{DD} = 380V,$ $R_{GEN} = 35\Omega,$ $I_{D} = 11A, V_{GS} = 10V,$	t _r		21		
Turn-Off Delay Time		t _{d(off)}		62		ns
Turn-Off Fall Time	$I_D = IIA$, $V_{GS} = IOV$,	t _f		28		
Source-Drain Diode (Note 4)						
Forward On Voltage	I _S = 11A, V _{GS} = 0V	V_{SD}			1.4	V
Reverse Recovery Time	V _B =200V, I _S = 5.5A	t _{rr}		226		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q _{rr}		2.1		μC

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. L = 50mH, $I_{AS} = 2.5A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^{\circ}C$
- 4. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.





ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM70N380CI C0G	ITO-220	50pcs / Tube
TSM70N380CH C5G	TO-251 (IPAK)	75pcs / Tube
TSM70N380CP ROG	TO-252 (DPAK)	2,500pcs / 13" Reel

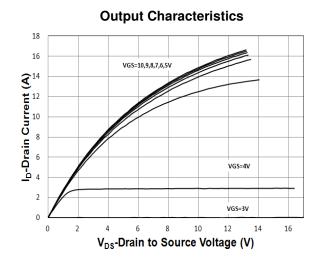
Note:

- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition

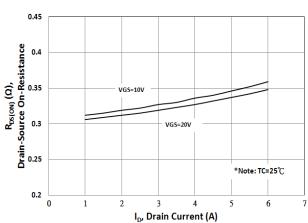


CHARACTERISTICS CURVES

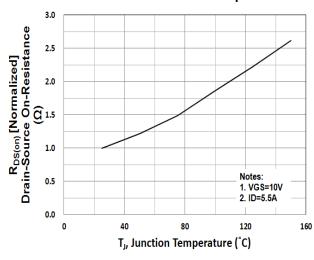
 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$



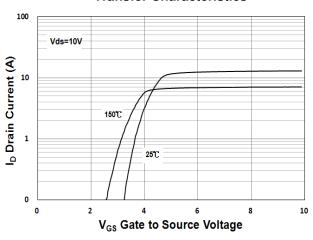
On-Resistance vs. Drain Current



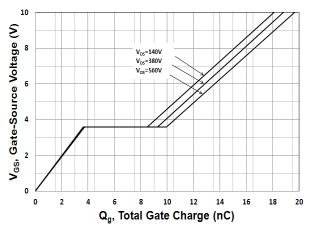
On-Resistance vs. Junction Temperature



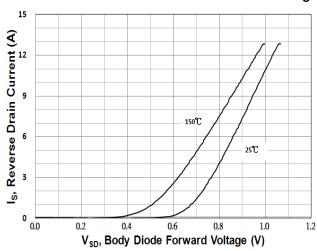
Transfer Characteristics



Gate-Source Voltage vs. Gate Charge



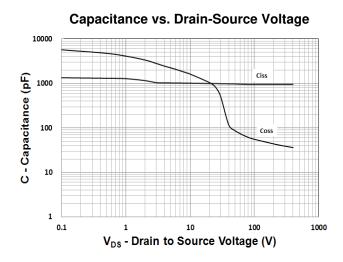
Source-Drain Diode Forward Current vs. Voltage

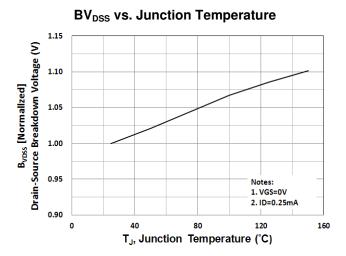




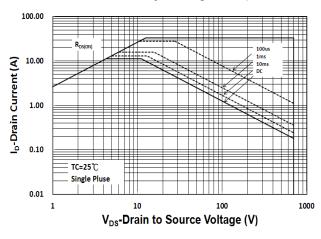
CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

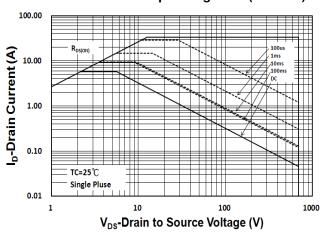




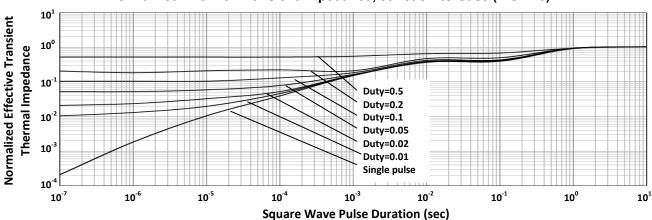




Maximum Safe Operating Area (ITO-220)



Normalized Thermal Transient Impedance, Junction-to-Case (ITO-220)



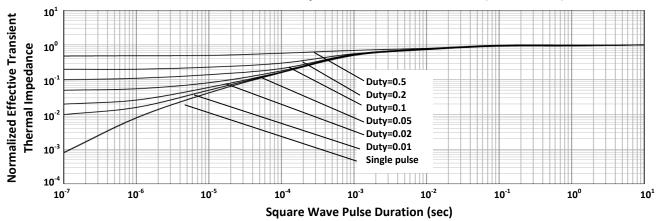
Version: E1706



ELECTRICAL CHARACTERISTICS CURVES

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

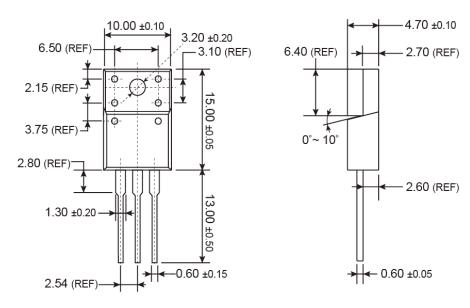
Normalized Thermal Transient Impedance, Junction-to-Case (DPAK/IPAK)





PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

ITO-220



MARKING DIAGRAM



G = Halogen Free

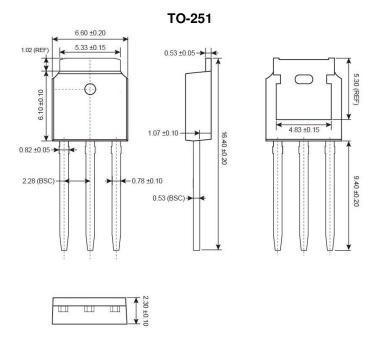
Y = Year Code

WW = Week Code $(01\sim52)$

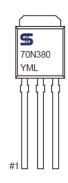
F = Factory Code



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

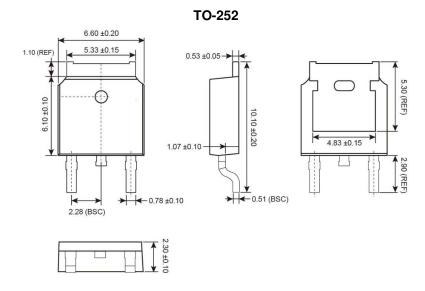
O =Jan P =Feb Q =Mar R =Apr S =May T =Jun U =Jul V =Aug

W = Sep X = Oct Y = Nov Z = Dec

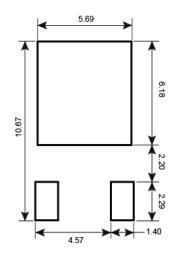
L = Lot Code $(1\sim9, A\sim Z)$



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S =May T =Jun U =Jul V =Aug W =Sep X =Oct Y =Nov Z =Dec

L = Lot Code $(1\sim9, A\sim Z)$





Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.